ne<mark>x</mark>peria

Important notice

Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

Instead of <u>http://www.nxp.com</u>, <u>http://www.philips.com/</u> or <u>http://www.semiconductors.philips.com/</u>, use <u>http://www.nexperia.com</u>

Instead of sales.addresses@www.nxp.com or sales.addresses@www.semiconductors.philips.com, use **salesaddresses@nexperia.com** (email)

Replace the copyright notice at the bottom of each page or elsewhere in the document, depending on the version, as shown below:

- © NXP N.V. (year). All rights reserved or © Koninklijke Philips Electronics N.V. (year). All rights reserved

Should be replaced with:

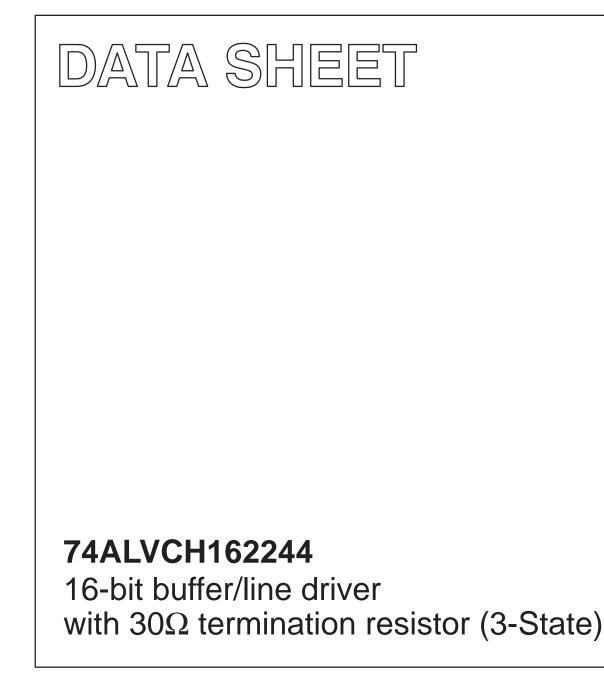
- © Nexperia B.V. (year). All rights reserved.

If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

INTEGRATED CIRCUITS



Product specification IC24 Data Handbook 1998 Jun 29



Philips Semiconductors

74ALVCH162244

FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- MULTIBYTETM flow-through standard pin-out architecture
- Low inductance multiple V_{CC} and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- Bus hold on all data inputs
- Integrated 30Ω termination resistor

DESCRIPTION

The 74ALVCH162244 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

The 74ALVCH162244 is a 16-bit non-inverting buffer/line driver with 3-State outputs. The device can be used as four 4-bit buffers, two 8-bit buffers or one 16-bit buffer. The 3-State outputs are controlled by the output enable inputs 10E and 20E. A HIGH on nOE causes the outputs to assume a high impedance OFF-state. The 74ALVCH162244 is designed with 30Ω series resistors in both HIGH and LOW output states.

The 74ALVCH162244 has active bus hold circuitry which is provided to hold unused or floating data inputs at a valid logic level. This feature eliminates the need for external pull-up or pull-down resistors.

PIN CONFIGURATIO		
10E 1	48	2 0E
1Y0 2	47	1A0
1Y1 3	46	1A1
GND 4	45	GND
1Y2 5	44	1A2
1Y3 6	43	1A3
V _{CC} 7	42	V _{CC}
2Y0 8	41	2A0
2Y1 9	40	2A1
GND 10	39	GND
2Y2 11	38	2A2
2Y3 12	37	2A3
3Y0 13	36	3A0
3Y1 14	35	3A1
GND 15	34	GND
3Y2 16	33	3A2
3Y3 17	32	3A3
V _{CC} [18	31	V _{CC}
4Y0 19	30	4A0
4Y1 20	29	4A1
GND 21	28	GND
4Y2 22	27	4A2
4Y3 23	26	4A3
4 0 E 24	25	3 0E
	SW00194	

PIN CONFIGURATION

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITION	TYPICAL	UNIT		
t _{PHL} /t _{PLH}	Propagation delay An to Yn	$V_{CC} = 2.5V, C_L = 30pF$ $V_{CC} = 3.3V, C_L = 50pF$	3.0 2.7	ns		
Cl	Input capacitance			5.0	pF	
C	Power dissipation experitores per huffer			25	ъĘ	
C _{PD}	Power dissipation capacitance per buffer	$V_{I} = GND$ to V_{CC}^{1}	Outputs disabled	4	pF	

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o) \text{ where: } f_i = \text{input frequency in MHz; } C_L = \text{output load capacitance in pF; } f_o = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V; } \Sigma (C_L \times V_{CC}^2 \times f_o) = \text{sum of the outputs.}$

ORDERING INFORMATION

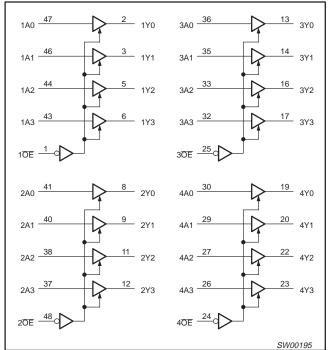
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	–40°C to +85°C	74ALVCH162244 DL	ACH162244 DL	SOT370-1
48-Pin Plastic TSSOP Type II	–40°C to +85°C	74ALVCH162244 DGG	ACH162244 DGG	SOT362-1

74ALVCH162244

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	1 0E	Output enable input (active LOW)
2, 3, 5, 6	1Y0 to 1Y3	Data outputs
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage
8, 9, 11, 12	2Y0 to 2Y3	
13, 14, 16, 17	3Y0 to 3Y3	Data outputs
19, 20, 22, 23	4Y0 to 4Y3	
24	4 0E	Output enable input (active LOW)
25	3 0E	Output enable input (active LOW)
30, 29, 27, 26	4A0 to 4A3	
36, 35, 33, 32	3A0 to 3A3	
41, 40, 38, 37	2A0 to 2A3	Data inputs
47, 46, 44, 43	1A0 to 1A3	
48	2 0E	Output enable input (active LOW)

LOGIC SYMBOL



FUNCTION TABLE

INP	OUTPUT	
nOE	nAn	nYn
L	L	L
L	Н	Н
н	Х	Z

H = HIGH voltage level L = LOW voltage level

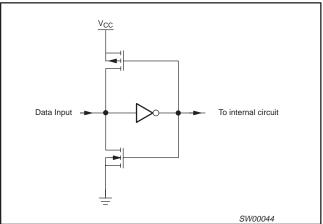
X = don't care

Z = high impedance OFF-state

LOGIC SYMBOL (IEEE/IEC)

10E	1	EN1				
2 0E	48	EN2				
3 0E	25	EN3				
4 0E	24	EN4				
	47					
1A0		-	1	1 🗸	2	1Y0
1A1	46				3	1Y1
1A2	44				5	1Y2
1A3	43	<u> </u>			6	1Y3
2A0	41	<u> </u>	1	2 ∇	8	2Y0
2A1	40			2 ,	9	2Y1
2A2	38				11	2Y2
2A3	37				12	2Y3
3A0	36	<u> </u>	4	0.17	13	3Y0
3A1	35		1	3 ∇	14	3Y1
	33	I			16	
3A2	32	ļ			17	3Y2
3A3	30					3Y3
4A0			1	4 ∇	19	4Y0
4A1	29	-			20	4Y1
4A2	27	-			22	4Y2
4A3	26	 			23	4Y3
		L			SWO	00060

BUS HOLD CIRCUIT



1998 Jun 29

74ALVCH162244

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT	
STWBUL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
	DC supply voltage 2.5V range (for max. speed performance @ 30 pF output load)		2.3	2.7	V
V _{CC}	DC supply voltage 3.3V range (for max. speed performance @ 50 pF output load)		3.0	3.6	V
VI	DC Input voltage range		0	V _{CC}	V
Vo	DC output voltage range		0	V _{CC}	V
T _{amb}	Operating free-air temperature range		-40	+85	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 2.3 \text{ to } 3.0 \text{V}$ $V_{CC} = 3.0 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
V ₁ DC input voltage		For data inputs with bus hold ¹	–0.5 to V _{CC} +0.5	V
VI		For control pins ¹	-0.5 to +4.6	v
I _{OK}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	±50	mA
Vo	DC output voltage	Note 1	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
Power dissipation per package -plastic medium-shrink (SSOP) -plastic thin-medium-shrink (TSSOP)		For temperature range: -40 to +125 °C above +55°C derate linearly with 11.3 mW/K above +55°C derate linearly with 8 mW/K	850 600	mW

NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

74ALVCH162244

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

				LIMITS		
SYMBOL	YMBOL PARAMETER	TEST CONDITIONS	Temp =	= -40°C to +8	5°C	UNI
		MIN	MIN TYP ¹			
		V _{CC} = 2.3 to 2.7V	1.7	1.2		.,
VIH	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0	1.5		V
		V _{CC} = 2.3 to 2.7V		1.2	0.7	v
VIL	LOW level Input voltage	V _{CC} = 2.7 to 3.6V		1.5	0.8	
		V_{CC} = 2.3 to 3.6V; V_I = V_{IH} or V_{IL} ; I_O = -100 μ A	V _{CC} -0.2	V _{CC}		
		V_{CC} = 2.3V; V_I = V_{IH} or V_{IL} ; I_O = -4mA	V _{CC} -0.4	V _{CC} -0.11		1
		V_{CC} = 2.3V; V_{I} = V_{IH} or V_{IL} ; I_{O} = -6mA	V _{CC} -0.6	V _{CC} -0.17		1
V _{OH}	HIGH level output voltage	V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} ; I_O = -4mA	V _{CC} -0.5	V _{CC} -0.09		V
		V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} ; I_O = -8mA	V _{CC} -0.7	V _{CC} -0.19		1
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -6mA$	V _{CC} -0.6	V _{CC} -0.13		1
		V_{CC} = 3.0V; V_I = V_{IH} or V_{IL} ; I_O = -12mA	V _{CC} -1.0	V _{CC} -0.27		1
		V_{CC} = 2.3 to 3.6V; $V_I = V_{IH}$ or V_{IL} ; I_O = 100 μ A		GND	0.20	
		V_{CC} = 2.3V; V_I = V_{IH} or V_{IL} ; I_O = 4mA		0.07	0.40	
		V_{CC} = 2.3V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 6mA		0.11	0.55	
V _{OL}	LOW level output voltage	V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} ; I_O = 4mA		0.06	0.40	V
		V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} ; I_O = 8mA		0.13	0.60	1
		V_{CC} = 3.0V; V_I = V_{IH} or V_{IL} ; I_O = 6mA		0.09	0.55	1
		V_{CC} = 3.0V; V_I = V_{IH} or $V_{IL;} I_O$ = 12mA		0.19	0.80	
I _I	Input leakage current	$V_{CC} = 2.3$ to 3.6V; $V_I = V_{CC}$ or GND		0.1	5	μA
I _{OZ}	3-State output OFF-state current			0.1	10	μA
I _{CC}	Quiescent supply current	V_{CC} = 2.3 to 3.6V; V_{I} = V_{CC} or GND; I_{O} = 0		0.2	40	μA
ΔI_{CC}	Additional quiescent supply current	V_{CC} = 2.3V to 3.6V; V_{I} = V_{CC} – 0.6V; I_{O} = 0		150	750	μA
12	Bus hold LOW sustaining current	$V_{CC} = 2.3V; V_I = 0.7V$	45	_		μA
I _{BHL} 2	Bus hold LOW sustaining current	$V_{CC} = 3.0V; V_I = 0.8V$	75	150] μ-
12	Bus hold HIGH sustaining current	$V_{CC} = 2.3V; V_I = 1.7V$	-45			μA
I _{BHH} ²		$V_{CC} = 3.0V; V_{I} = 2.0V$	-75	-175		μ
I _{BHLO} 2	Bus hold LOW overdrive current	$V_{CC} = 3.6V$	500			μA
I _{BHHO} 2	Bus hold HIGH overdrive current	$V_{CC} = 3.6V$	-500			μA

NOTES:

1. All typical values are at $T_{amb} = 25^{\circ}C$. 2. Valid for data inputs of bus hold parts.

74ALVCH162244

AC CHARACTERISTICS FOR V_{CC} = 2.3V TO 2.7V RANGE AND V_{CC} < 2.3V

 $GND = 0V; t_r = t_f \le 2.0ns; C_L = 30pF$

SYMBOL	PARAMETER	TER WAVEFORM V _{CC} = 2.3 to 2.7V		UNIT		
			MIN	TYP ¹	MAX	
t _{PHL} /t _{PLH}	Propagation delay nAn to nYn	1, 3	1.0	3.0	4.9	ns
t _{PZH} /t _{PZL}	3-State output enable time nOE to nYn	2, 3	1.0	4.0	6.8	ns
t _{PHZ} /t _{PLZ}	3-State output disable time	2, 3	1.0	2.3	6.3	ns

NOTES:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$ and $V_{CC} = 2.5V$.

AC CHARACTERISTICS FOR V_{CC} = 3.0V TO 3.6V RANGE AND V_{CC} = 2.7V

GND = 0V; $t_r = t_f \le 2.5ns$; $C_L = 50pF$

			LIMITS						
SYMBOL	PARAMETER	WAVEFORM	V_{CC} = 3.3 \pm 0.3V		$= 3.3 \pm 0.3 V$ V _{CC} = 2.7V				UNIT
			MIN	TYP ^{1, 2}	MAX	MIN	TYP ¹	MAX	
t _{PHL} /t _{PLH}	Propagation delay nAn to nYn	1, 3	1.0	2.7	4.2	1.0	3.3	4.7	ns
t _{PZH} /t _{PZL}	3-State output enable time nOE to nYn	2, 3	1.0	3.5	5.6	1.0	4.6	6.7	ns
t _{PHZ} /t _{PLZ}	3-State output disable time	2, 3	1.0	2.9	5.5	1.0	3.2	5.7	ns

NOTES:

1. All typical values are measured at $T_{amb} = 25^{\circ}C$.

2. Typical value is measured at $V_{CC} = 3.3V$

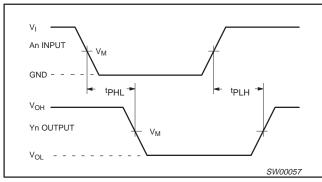
74ALVCH162244

AC WAVEFORMS FOR V_{CC} = 2.3V TO 2.7V AND V_{CC} < 2.3V RANGE

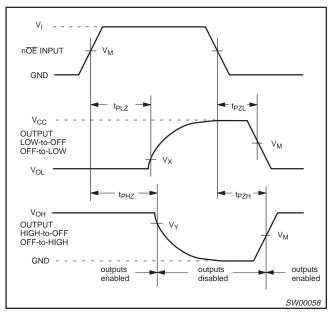
 $\label{eq:VM} \begin{array}{l} V_M = 0.5 \; V_{CC} \\ V_X = V_{OL} + 0.15 V \\ V_Y = V_{OH} - 0.15 V \\ V_{OL} \; \text{and} \; V_{OH} \; \text{are the typical output voltage drop that occur with the output load.} \\ \end{array}$

AC WAVEFORMS FOR V_{CC} = 3.0V TO 3.6V AND V_{CC} = 2.7V RANGE

 $\begin{array}{l} V_M = 1.5 \ V \\ V_X = V_{OL} + 0.3 V \\ V_Y = V_{OH} - 0.3 V \\ V_{OL} \ \text{and} \ V_{OH} \ \text{are the typical output voltage drop that occur with the output load.} \\ \end{array}$

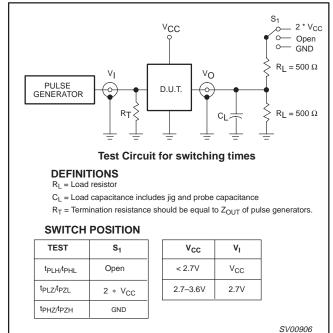


Waveform 1. Input (An) to output (Yn) propagation delay times



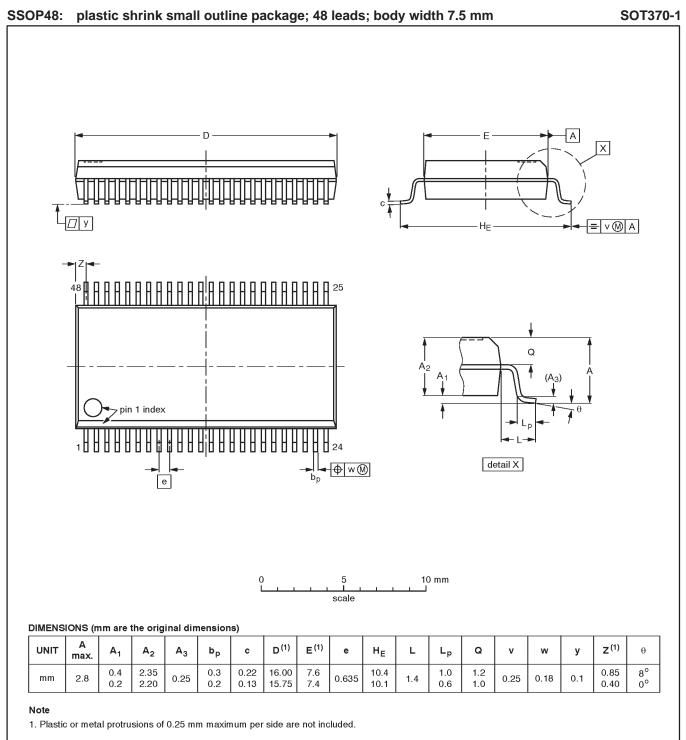
Waveform 2. 3-State enable and disable times

TEST CIRCUIT



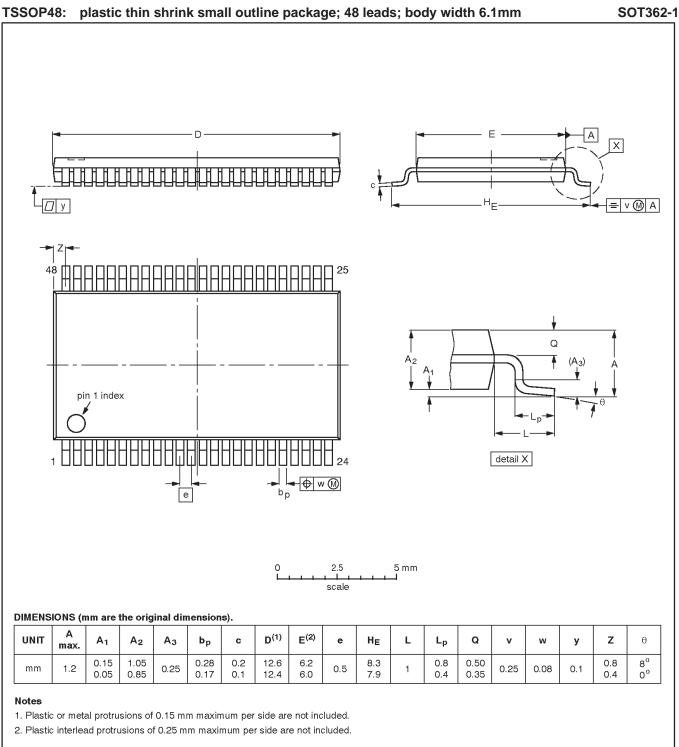
Waveform 3. Load circuitry for switching times

74ALVCH162244



OUTLINE	TLINE REFERENCES		EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT370-1		MO-118AA				-93-11-02 95-02-04	

74ALVCH162244



OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE
SOT362-1		MO-153ED				- 93-02-03 95-02-10

74ALVCH162244

NOTES

74ALVCH162244

Data sheet status

Data sheet status	Product status	Definition ^[1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

[1] Please consult the most recently issued datasheet before initiating or completing a design.

Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Disclaimers

Life support — These products are not designed for use in life support appliances, devices or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Philips Semiconductors 811 East Arques Avenue P.O. Box 3409 Sunnyvale, California 94088–3409 Telephone 800-234-7381 © Copyright Philips Electronics North America Corporation 1998 All rights reserved. Printed in U.S.A.

Date of release: 06-98

Document order number:

9397-750-04537

Let's make things better.



